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Kano
10/17/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **KANO et al.**

Group Art Unit: 2812

Serial No.: 09/941,982

Examiner: **Mulpuri, Savitri**

Filed: **August 30, 2001**

P.T.O. Confirmation No.: 7536

For. **METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR LAYER, AND
METHOD OF MANUFACTURING NITRIDE-BASED SEMICONDUCTOR
DEVICE**

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Date: October 9, 2003

Sir:

Prior to continued examination, please amend the above-identified application as follows:

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OCT 15 2003

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Docket No.: 011083

Filed: August 30, 2001

Issued:



U.S. Patent Application

Serial No.: 09/941,982

Patent Number:

Applicant(s): KANO et al.

Papers filed herewith on: 10/09/03

Fee: \$1,190.00

RCE; 2 month EOT; Preliminary Amendment and Change

COMMISSIONER OF PATENTS

Receipt is hereby acknowledged of the papers filed as indicated in connection with the above-identified case.

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